NSN 5962-01-339-0851

Memory Microcircuit - Page 1 of 1

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Body Length: 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.150 inches and 0.210 inches **Maximum Power Dissipation Rating:** 1.04 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and w/enable and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source and 5.5 volts input Memory Device Type: Prom **Memory Capacity:** 8kx8 **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a Unit Of Measure: **Demilitarization:** Yes - demil/mli Fiig: A458a0